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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Applicant Hiroaki Niimi, et al.

Docket Number: TI-32705

Serial No.: 09/885,744

Art Unit: 2823

Filed: 06/20/01

Examiner: Khiem D. Nguyen

For: Method for Annealing Ultra-Thin, High Quality Gate Oxide
Layers Using Oxidizer/Hydrogen Mixtures

CERTIFICATION OF FACSIMILE TRANSMISSION

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<input type="checkbox"/> CONTINUATION APP'N (# Pages)	<input type="checkbox"/> ELECTION
<input type="checkbox"/> DIVISIONAL APP'N	
NAME OF INVENTOR(S): Hiroaki Niimi et al.	
TITLE OF INVENTION: Method for Annealing Ultra-Thin, High Quality Gate Oxide Layers Using Oxidizer/Hydrogen Mixtures	
TI FILE NO.: TI-32705	DEPOSIT ACCT. NO.: 20-0668
FAXED: 11-19-03 DUE: 11-19-03 ATTY/SEC'Y: GCH/kjv	
RECEIPT DATE & SERIAL NO.: Serial No.: 09/885,744 Filing Date: 06/20/01	

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Texas Instruments Incorporated
PO Box 655474, M/S 3999
Dallas, TX 75265-5474

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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TI-32705

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NOTICE OF APPEAL FROM THE PRIMARY EXAMINER TO THE BOARD OF APPEALS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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Sir:

Karen Vertz
Karen Vertz

11-19-03
Date

Applicants hereby appeal to the Board of Appeals from the decision dated August 19, 2003 of the Primary Examiner finally rejecting claims 1-7 and 9-13.

The item(s) checked below are appropriate:

1. ☐ An extension of time to respond to the final rejection
☐ was granted on _____.
☐ is requested for _____ month(s).
2. ☐ A timely response to the final rejection has been filed, as provided in 841 O.G. 1411.
3. ☒ Fee \$330.00:
☐ Not required (Fee paid in prior appeal)
☒ The Commissioner of Patents is hereby authorized to charge any fees which may be required, or credit any overpayment to Deposit Account No. 20-0668 of Texas Instruments Incorporated. **This form is submitted in triplicate.**

Signature [Rule 191(b)]

Post Office Address (to which correspondence is to be sent)
Texas Instruments Incorporated
P.O. Box 655474, MS 3999
Dallas, TX 75265
(972) 470-0130

Gary C. Honeycutt
Gary C. Honeycutt
Reg. No. 20,250
Attorney for Appellants